

Vera Logacheva

List of Publications by Year in descending order

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#	ARTICLE	IF	CITATIONS
1	Synthesis and Optical Properties of Cobalt-Modified Titanium Oxide Films. Optics and Spectroscopy (English Translation of Optika i Spektroskopiya), 2019, 126, 674-680.	0.2	3
2	Синтез и оптические свойства тонких пленок оксидов титана и кобальта. Оптика и спектроскопия, 2019, 126, 674-680.	0.2	3
3	Cobalt Modification of Thin Rutile Films Magnetron-Sputtered in Vacuum. Technical Physics, 2018, 63, 605-611.	0.2	2
4	Interdiffusion and phase formation in the Fe ²⁺ /TiO ₂ thin-film system. Semiconductors, 2017, 51, 1300-1305.	0.2	1
5	Growth and structure of PbWO ₄ films. Inorganic Materials, 2012, 48, 298-303.	0.2	5
6	Niobium, indium, and tin heterodiffusion during formation of two-layer systems on silicon single crystals. Russian Journal of Inorganic Chemistry, 2011, 56, 771-775.	0.3	1
7	Redistribution of components in the niobium-silicon system under high-temperature proton irradiation. Semiconductors, 2011, 45, 1617-1619.	0.2	1
8	Component redistribution during Nb and In/Nb film growth on single-crystal silicon. Inorganic Materials, 2009, 45, 998-1002.	0.2	1
9	Investigation of oxidation process and properties of indium and tin-based thin-film heterostructures. Journal of Surface Investigation, 2008, 2, 444-449.	0.1	1
10	Phase composition and optical properties of thin films based on lanthanum and tungsten oxides. Inorganic Materials, 2008, 44, 1125-1129.	0.2	2
11	Growth of niobium oxide films on single-crystal silicon. Inorganic Materials, 2007, 43, 1230-1234.	0.2	11
12	WO ₃ films prepared by thermal oxidation of magnetron-sputtered tungsten: Synthesis and properties. Russian Journal of Inorganic Chemistry, 2007, 52, 1201-1205.	0.3	2
13	Dielectric properties of lead zirconate titanate films synthesized through oxidation of metal layers. Physics of the Solid State, 2007, 49, 754-758.	0.2	0
14	Effect of vacuum annealing on the phase composition of In/SnO/Si, In/SnO ₂ /Si, and Sn/In ₂ O ₃ /Si heterostructures. Inorganic Materials, 2006, 42, 108-111.	0.2	8
15	Interaction of Pb and Sn with Thin Films of Their Oxides on Single-Crystal Silicon. Inorganic Materials, 2004, 40, 400-403.	0.2	1
16	Phase Composition and Dielectric Properties of Thin Films Produced by Annealing Sn/Pb/Ti/Si and Pb/Sn/Ti/Si Heterostructures. Inorganic Materials, 2004, 40, 1079-1082.	0.2	1
17	Preparation of Thin Lead Stannate Layers on Single-Crystal Silicon. Inorganic Materials, 2003, 39, 1079-1087.	0.2	1
18	Lead titanate ferroelectric films on single-crystal silicon. Physics of the Solid State, 2002, 44, 774-778.	0.2	5

#	ARTICLE	IF	CITATIONS
19	Thermal Oxidation of Ti and Pb Thin Films Deposited on Single-Crystal Silicon. Inorganic Materials, 2001, 37, 466-468.	0.2	1